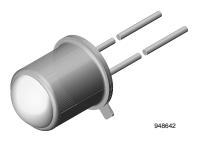
BPW24R

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Silicon PIN Photodiode, RoHS-Compliant



DESCRIPTION

BPW24R is a high sensitive silicon planar photodiode in a standard TO-18 hermetically sealed metal case with a glass lens.

A precise alignment of the chip gives a good coincidence of mechanical and optical axes. The device features a low capacitance and high speed even at low supply voltages.

FEATURES

- Package type: leaded
- Package form: TO-18
- Dimensions (in mm): Ø 4.7
- Radiant sensitive area (in mm²): 0.88
- High photo sensitivity
- · High sensitivity
- · Suitable for visible and near infrared radiation
- · Fast response times
- Angle of half sensitivity: $\varphi = \pm 12^{\circ}$
- · Hermetically sealed package
- · Cathode connected to package
- · Central chip alignment
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

APPLICATIONS

High speed photo detector

PRODUCT SUMMARY				
COMPONENT	I _{ra} (μΑ)	φ (°)	λ _{0.5} (nm)	
BPW24R	60	± 12	610 to 1040	

Note

Test condition see table "Basic Characteristics"

ORDERING INFORMATION				
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM	
BPW24R	Bulk	MOQ: 1000 pcs, 1000 pcs/bulk	TO-18	

Note

• MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Reverse voltage		V _R	60	V	
Power dissipation	T _{amb} ≤ 25 °C	Pv	210	mW	
Junction temperature		Tj	125	°C	
Operating temperature range		T _{amb}	-40 to +125	°C	
Storage temperature range		T _{stg}	-40 to +125	°C	
Soldering temperature	t ≤ 5 s	T _{sd}	260	°C	
Thermal resistance junction to ambient	Connected with Cu wire, 0.14 mm ²	R _{thJA}	350	K/W	







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BASIC CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Breakdown voltage	I _R = 100 μA, E = 0	V _(BR)	60	200	-	V
Reverse dark current	$V_{R} = 20 V, E = 0$	I _{ro}	-	2	10	nA
Diode capacitance	$V_{R} = 0 V, f = 1 MHz, E = 0$	CD	-	11	-	pF
	$V_{R} = 5 V, f = 1 MHz, E = 0$	CD	-	3.8	-	pF
	V _R = 20 V, f = 1 MHz, E = 0	CD	-	2.5	-	pF
Open circuit voltage	$E_e = 1 \text{ mW/cm}^2$, $\lambda = 950 \text{ nm}$	Vo	-	450	-	mV
Temperature coefficient of Vo	$E_e = 1 \text{ mW/cm}^2$, $\lambda = 950 \text{ nm}$	TK _{Vo}	-	-2	-	mV/K
Short circuit current	$E_e = 1 \text{ mW/cm}^2$, $\lambda = 950 \text{ nm}$	l _k	-	55	-	μA
Temperature coefficient of I_k	E _V = 1 klx	TK _{lk}	-	0.1	-	%/K
Reverse light current	$E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm},$ $V_R = 20 \text{ V}$	I _{ra}	45	60	-	μA
Angle of half sensitivity		φ	-	± 12	-	0
Wavelength of peak sensitivity		λρ	-	940	-	nm
Range of spectral bandwidth		λ _{0.5}	610	-	1040	nm
Rise time	$V_R = 10 \text{ V}, \text{ R}_L = 50 \Omega, \lambda = 830 \text{ nm}$	t _r	-	80	-	ns
Fall time	$V_R = 10 \text{ V}, \text{ R}_L = 50 \Omega, \lambda = 830 \text{ nm}$	t _f	-	60	-	ns

BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

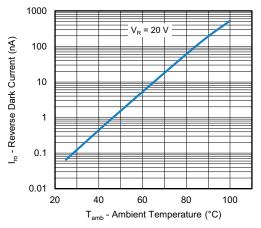


Fig. 1 - Reverse Dark Current vs. Ambient Temperature

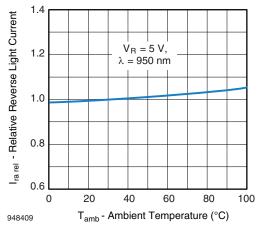


Fig. 2 - Relative Reverse Light Current vs. Ambient Temperature

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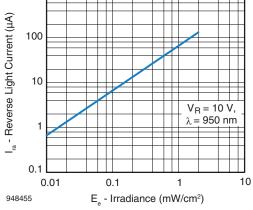


Fig. 3 - Reverse Light Current vs. Irradiance

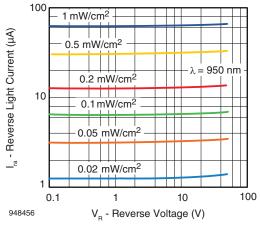


Fig. 4 - Reverse Light Current vs. Reverse Voltage

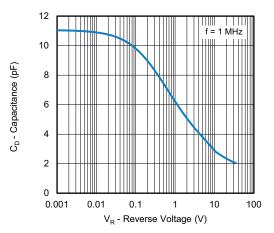


Fig. 5 - Diode Capacitance vs. Reverse Voltage

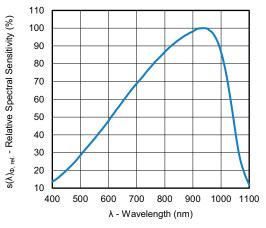


Fig. 6 - Relative Spectral Sensitivity vs. Wavelength

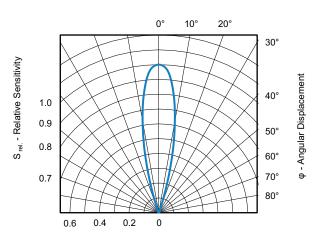


Fig. 7 - Relative Radiant Sensitivity vs. Angular Displacement

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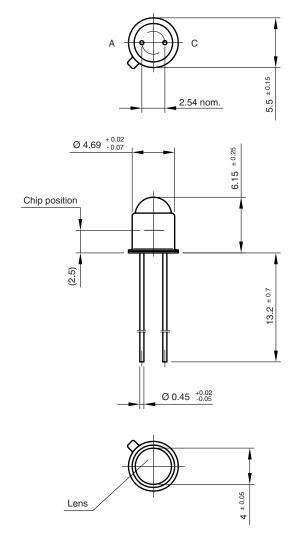
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PACKAGE DIMENSIONS in millimeters





technical drawings according to DIN specifications

Drawing-No.: 6.503-5022.02-4 Issue: 1; 24.08.98 14487



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Revision: 01-Jan-2025

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